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(54) **OLED DISPLAY PANEL AND DISPLAY DEVICE**

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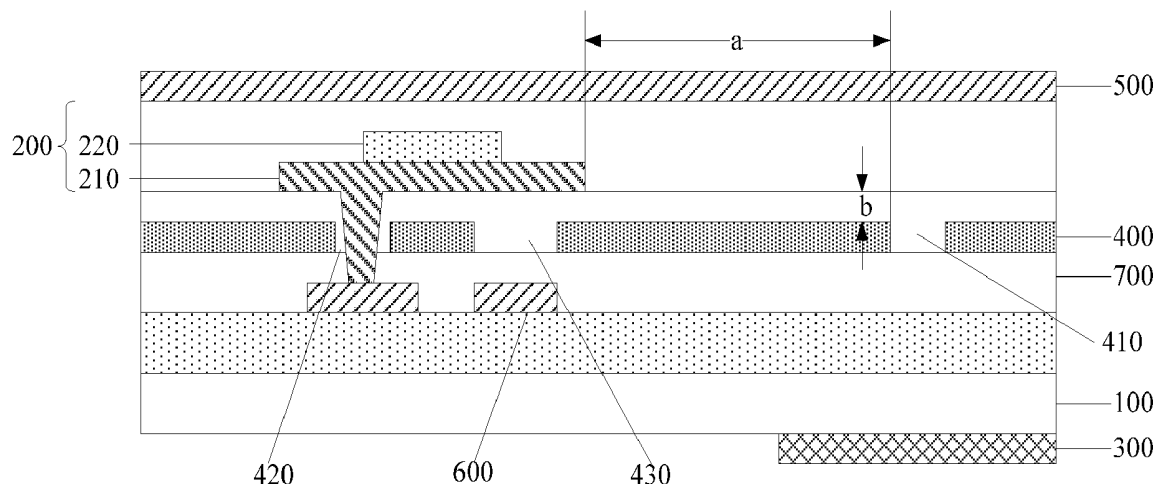
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(57)

ABSTRACT

An OLED display panel and a display device are provided. An image sensor is added below OLED light-emitting devices, a light shielding layer including at least one pinhole imaging region is added between the image sensor and the OLED light emitting device, with the pinhole imaging region corresponding to a gap position between the OLED light-emitting devices in the light shielding layer and staggered from light shielding parts in a signal routing and a control device, an object located above the OLED display panel is imaged on the image sensor.

17 Claims, 4 Drawing Sheets



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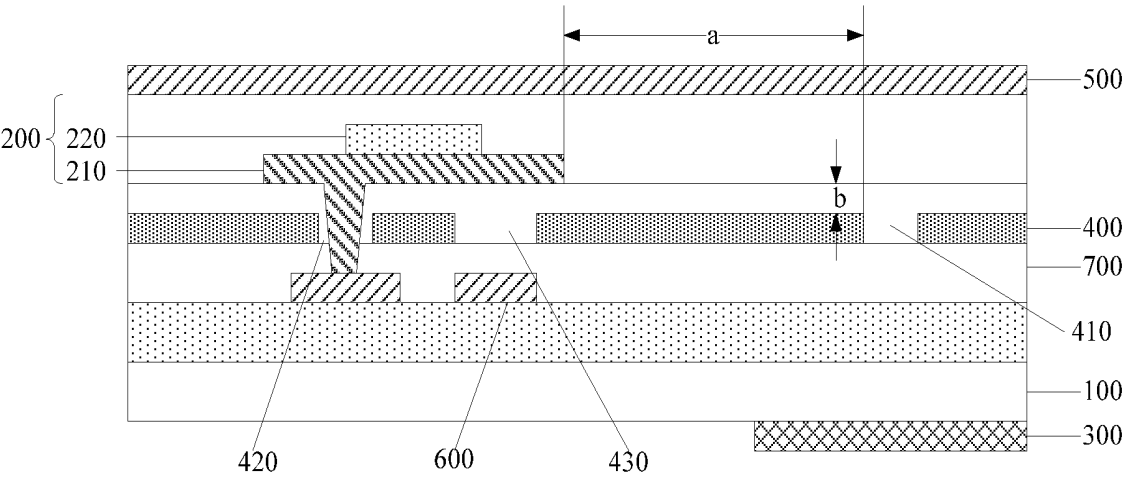


FIG. 1

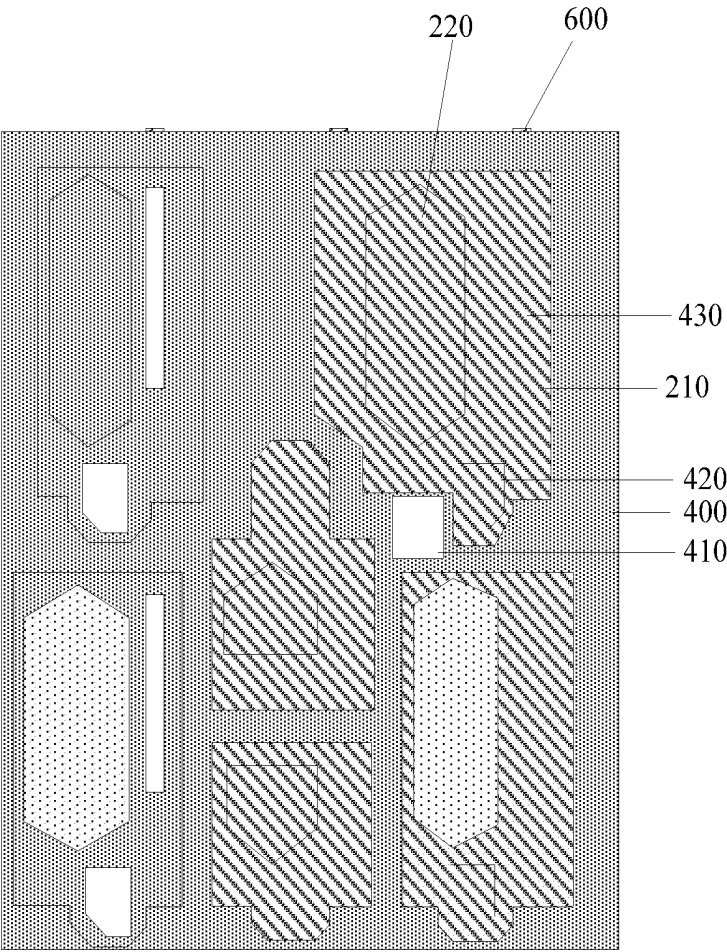


FIG. 2

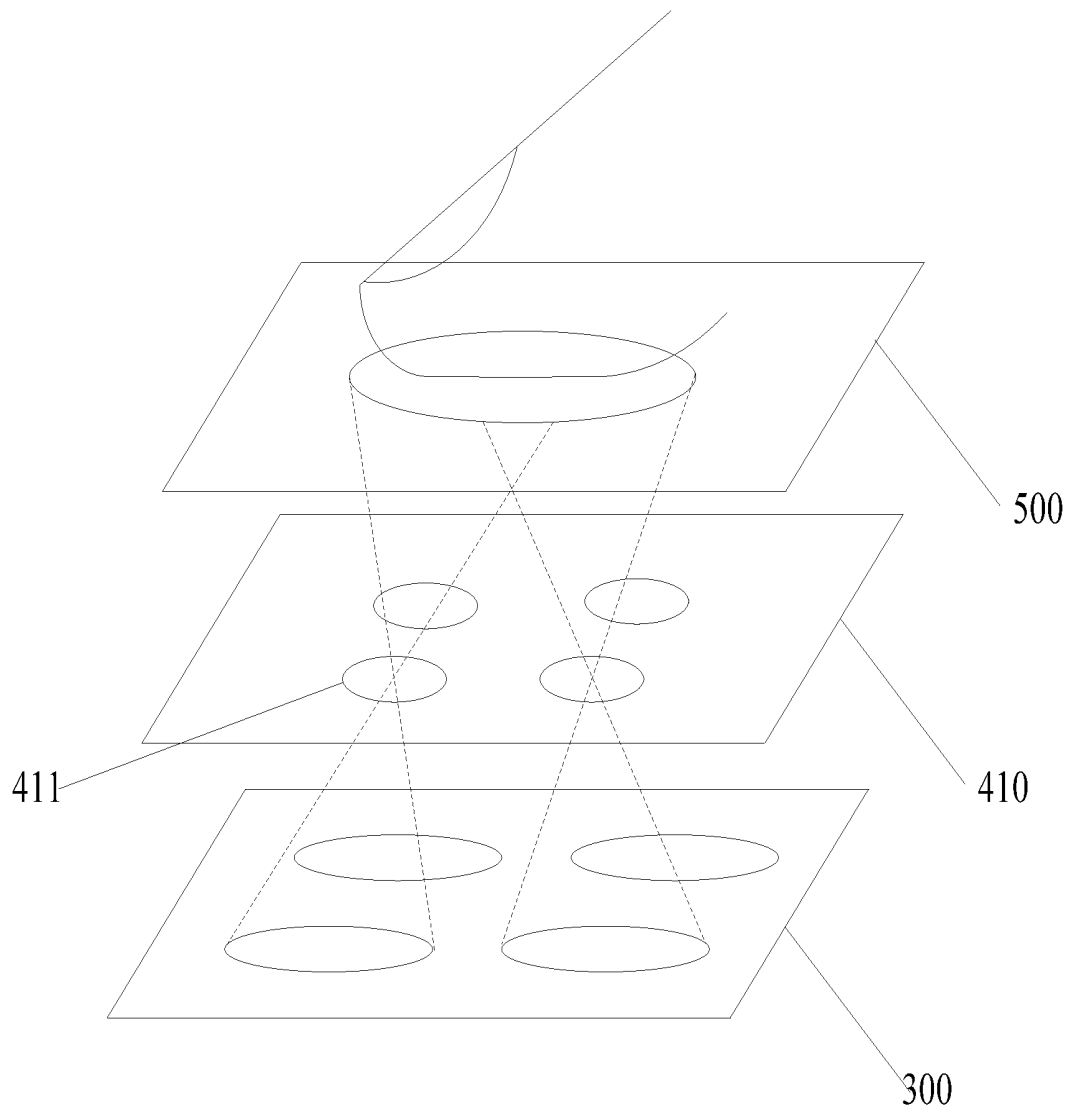


FIG. 3a

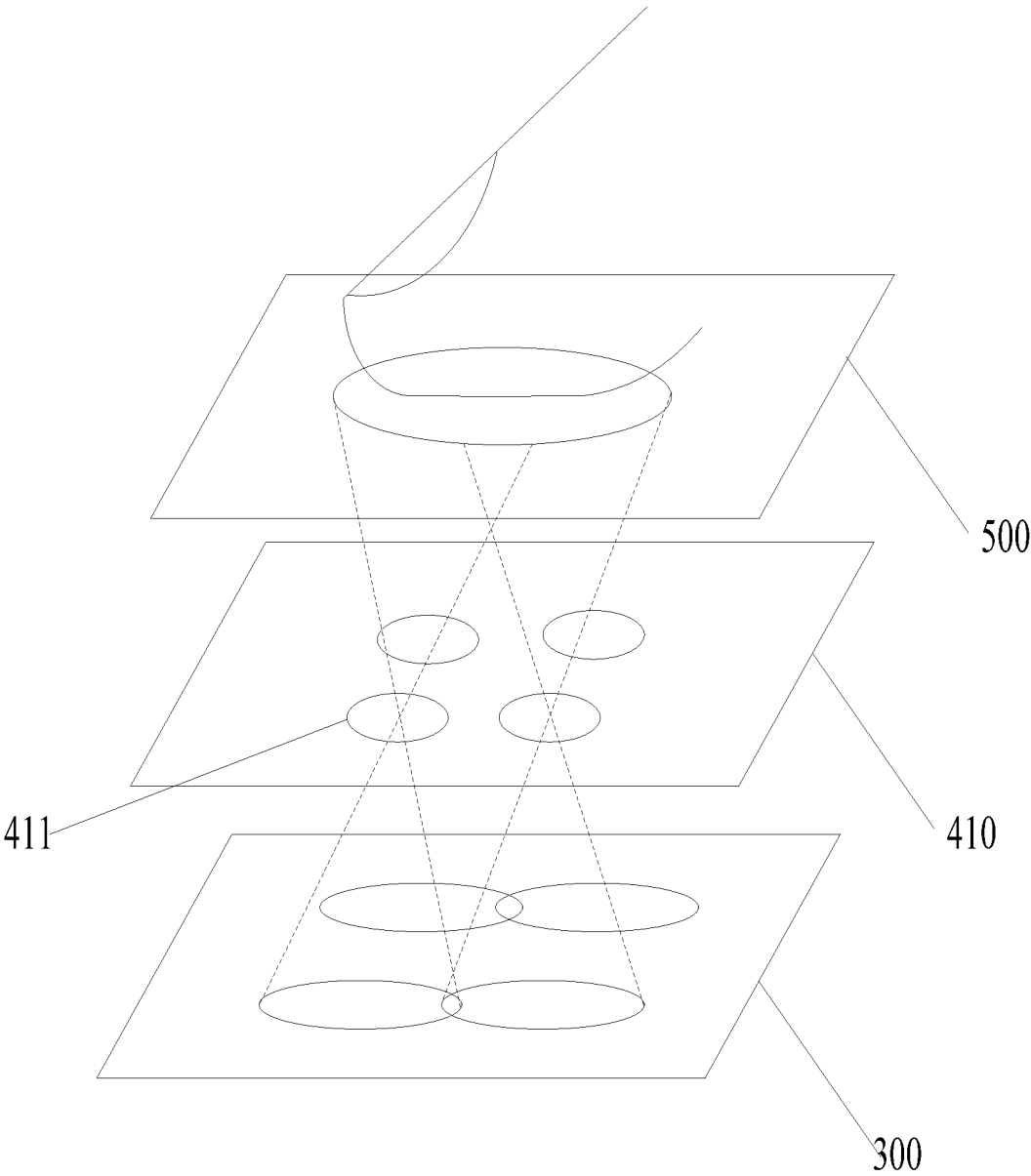


FIG. 3b

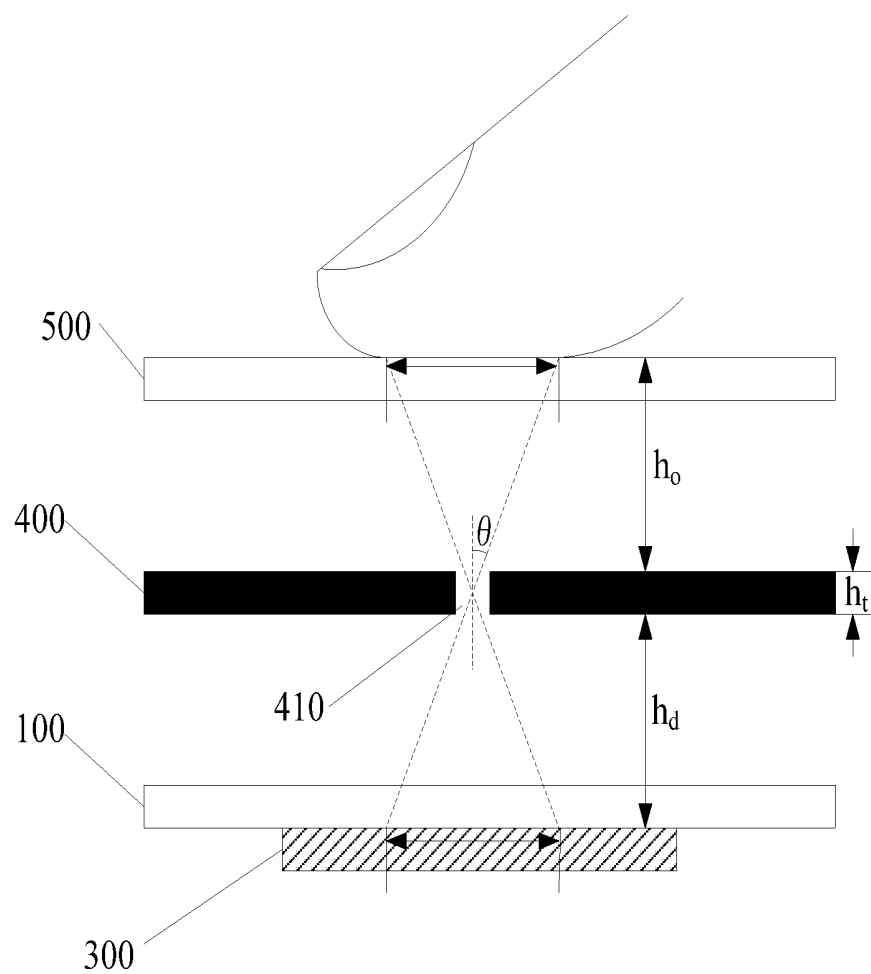


FIG. 4

OLED DISPLAY PANEL AND DISPLAY DEVICE

CROSS REFERENCE TO RELATED APPLICATIONS

This application is the National Stage of PCT/CN2017/088081 filed on Jun. 13, 2017, which claims priority under 35 U.S.C. § 119 of Chinese Application No. 201611207500.8 filed on Dec. 23, 2016, the disclosure of which is incorporated by reference.

TECHNICAL FIELD

Embodiments of the present disclosure relate to an OLED display panel and a display device.

BACKGROUND

An Organic Light-Emitting Diode (OLED) display panel has a trend of developing into narrow frame and whole surface display. Additional fingerprint recognition, a camera, a microphone and the like on a whole surface of a traditional OLED display panel cannot meet new requirements of users, and other fingerprint recognition manners need to be developed.

SUMMARY

Embodiments of the present disclosure relate to an OLED display panel and a display device, which can realize the fingerprint recognition function in the display area of the OLED display panel.

At least one embodiment of the present disclosure provides an OLED display panel, comprising: a substrate; a plurality of OLED light-emitting devices arranged on a side of the substrate; a signal routing and a control device correspondingly connected with the OLED light-emitting devices; an image sensor arranged on the other side or the same side of the substrate; and a light shielding layer arranged between the image sensor and a film layer where the OLED light-emitting devices are located, the light shielding layer comprising at least one pinhole imaging region.

An orthographic projection position of the pinhole imaging region on the substrate is arranged at a gap position between the OLED light-emitting devices, and is staggered from orthographic projection positions of light shielding parts in the signal routing and the control device on the substrate.

The image sensor is configured to acquire an image formed after an object above the OLED display panel passes through the pinhole imaging region.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the pinhole imaging region comprises a plurality of holes distributed in an array.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, in a pinhole imaging region, a center distance d between every two adjacent holes satisfies one of the following or a combination relationship: $d < 2 * (h_o + h_f/2) * \tan(\arcsin(1/n))$, $d > 2 * (h_o + h_f/2) * \tan(\arcsin(1/n))$; where n is a refractive index of a film layer in contact with a receiving surface of the image sensor, h_o is a distance between a lower surface of the light shielding layer and an upper surface of the image sensor, h_f is a thickness of the light shielding layer, and h_o is

a distance between an upper surface of the light shielding layer and an upper surface of the OLED display panel.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, each hole has a diameter in a range of 5 μm to 20 μm .

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the pinhole imaging region and a corresponding OLED light-emitting device of the closest to the pinhole imaging region satisfy a following relationship: a horizontal distance between the pinhole imaging region and the corresponding OLED light-emitting device closest to the pinhole imaging region is larger than a vertical distance between the pinhole imaging region and the corresponding OLED light-emitting device closest to the pinhole imaging region.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the signal routing comprises a data line arranged between the film layer where the OLED light-emitting devices are located and the substrate; the light shielding layer is arranged between the film layer where the OLED light-emitting devices are located and a film layer where the data line is located; and the light shielding layer further comprises: a connecting through hole configured to connect a drain electrode in the film layer where the data line is located, or a pattern comprising the drain electrode with an anode in the OLED light-emitting device.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer; and an orthographic projection of the anode in the OLED light-emitting device on the substrate covers an orthographic projection of the connecting through hole.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the signal routing included in the film layer where the data line is located is a data line; and the light shielding layer is configured into a conductive layer loading a direct current voltage signal.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the light shielding layer further comprises a hollow region arranged above at least a part of the data line; and the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer, and an orthographic projection of the anode on the substrate covers an orthographic projection of the hollow region.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the data line has a line width larger than 2.3 μm , and the film layer where the data line is located has a thickness less than 700 nm.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the line width of the data line is 3.5 μm , and the thickness of the film layer where the data line is located is 500 nm.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the anode in the OLED light-emitting device has an area larger than that of a light-emitting layer in the OLED light-emitting device.

In a possible implementation, in the OLED display panel provided by the embodiment of the present disclosure, the image sensor is arranged in a whole surface manner, or is only arranged below the pinhole imaging region.

Embodiments of the present disclosure also provide a display device, comprising any one of the OLED display devices.

BRIEF DESCRIPTION OF THE DRAWINGS

The embodiments of the present disclosure are illustrated in more details in connection with the drawings, so that those skilled in the art can understand the embodiments of the present disclosure more clearly, in which:

FIG. 1 is a schematically structural side view of an OLED display panel provided by an embodiment of the present disclosure;

FIG. 2 is a schematically structural top view of the OLED display panel provided by the embodiment of the present disclosure;

FIGS. 3a and 3b are respectively schematic diagrams of working principle of a pinhole imaging region of the OLED display panel provided by an embodiment of the present disclosure; and

FIG. 4 is a schematic diagram of working principle of pinhole imaging of an OLED display panel provided by another embodiment of the present disclosure.

DETAILED DESCRIPTION

Technical solutions of the embodiment will be described in a clearly and fully understandable way in conjunction with the drawings related to the embodiments of the disclosure. It is apparent that the described embodiments are just a part but not all of the embodiments of the disclosure. Based on the described embodiments herein, those skilled in the art can obtain other embodiment(s), without any creative work, which shall be within the scope of the disclosure.

Unless otherwise defined, all the technical and scientific terms used herein have the same meanings as commonly understood by one of ordinary skill in the art to which the present disclosure belongs. The terms, such as “first,” “second,” or the like, which are used in the description and the claims of the present disclosure, are not intended to indicate any sequence, amount or importance, but for distinguishing various components. The terms, such as “comprise/comprising,” “include/including,” or the like are intended to specify that the elements or the objects stated before these terms encompass the elements or the objects and equivalents thereof listed after these terms, but not preclude other elements or objects. The terms, such as “connect/connecting/connected,” “couple/coupling/coupled” or the like, are not limited to a physical connection or mechanical connection, but may include an electrical connection/coupling, directly or indirectly. The terms, “on,” “under,” “left,” “right,” or the like are only used to indicate relative position relationship, and when the position of the object which is described is changed, the relative position relationship may be changed accordingly.

The inventors noticed that a fingerprint recognition technology developed in an active area (AA) of a display panel can effectively reduce attached regions of an OLED display panel to achieve whole surface display.

Specific implementation manners of an OLED display panel and a display device provided by embodiments of the present disclosure are illustrated in detail in conjunction with the drawings.

The embodiment of the present disclosure provides an OLED display panel, as shown in FIG. 1, comprising: a substrate 100, a plurality of OLED light-emitting devices 200 arranged on a side of the substrate 100, a signal routing

and a control device correspondingly connected with the OLED light-emitting devices 200, an image sensor 300 arranged on the other side or the same side of the substrate 100, and a light shielding layer 400 arranged between the image sensor 300 and a film layer where the OLED light-emitting devices 200 are located, the light shielding layer 400 having at least one pinhole imaging region 410.

As shown in FIG. 2, a region of an orthographic projection of the pinhole imaging region 400 on the substrate 100 is arranged at a corresponding gap position between the OLED light-emitting devices 200, and is staggered from regions of orthographic projections of light shielding parts in the signal routing and the control device on the substrate 100.

The image sensor 300 is used for acquiring an image formed after an object above the OLED display panel passes through the pinhole imaging region 410. For example, when a finger is placed on a surface of the OLED display panel, the image sensor 300 can recognize fingerprints and perform touch detection.

According to the OLED display panel provided by the embodiment of the present disclosure, the image sensor 300 is added below the OLED light-emitting device 200, and the light shielding layer 400 having at least one pinhole imaging region 410 is added between the image sensor 300 and the OLED light-emitting device 200; by arranging the pinhole imaging region 410 corresponding to a gap position between the OLED light-emitting devices 200 in the light shielding layer 400 and staggered from the light shielding parts in the signal routing and the control device, the object located above the OLED display panel is imaged on the image sensor 300. For example, when a finger is placed above the OLED display panel corresponding to the pinhole imaging region 410, fingerprint acquiring and recognizing functions can be achieved. In this way, a fingerprint recognizing function can be achieved in an active area of the OLED display panel, and attached regions of the whole device are reduced, so that a bezelless design is achieved.

In the OLED display panel provided by the embodiment of the present disclosure, the image sensor 300 can be arranged on a back side of the substrate 100 as shown in FIG. 1, and can also be arranged on a front side (namely a surface where the OLED light-emitting device is formed) of the substrate, and the embodiments of the present disclosure are not limited thereto. For example, the image sensor 300 can also be arranged in a whole surface manner, and can also be only arranged below the pinhole imaging region 410 as shown in FIG. 1, and the embodiments of the present disclosure are not limited thereto. For example, a CCD and other devices can be adopted by the image sensor 300 to achieve an image detection function. Hereinafter, illustration is performed in an example in which the image sensor 300 is arranged on the back side of the substrate 100, but the embodiments of the present disclosure are not limited thereto.

In the OLED display panel provided by the embodiment of the present disclosure, the control device correspondingly connected with the OLED light-emitting devices 200, for example, can be a control circuit including a plurality of transistors, the structure of the control device can have a plurality of implementation manners, and the light shielding part of the control device refers to a gate electrode, a source electrode, a drain electrode and other parts in the transistors having a shielding effect on the light.

When the fingerprint recognition is performed by adopting a pinhole imaging principle, the imaging at the center of the pinhole is clear, and the closer to the edge of the pinhole,

the obscurer the imaging is. In the OLED display panel provided by the embodiment of the present disclosure, a phenomenon that imaging on the edge is obscure is avoided in a manner that each pinhole imaging region **410** is provided with a plurality of holes **411**. For example, as shown in FIGS. **3a** and **3b**, a plurality of holes **411** in an array are formed in the pinhole imaging region **410**. As shown in FIGS. **3a** and **3b**, 2*2 holes **411** are formed in the pinhole imaging region **410**, however, the embodiments of the present disclosure are not limited thereto.

For example, each hole **411** in the pinhole imaging region **410** can image part of a fingerprint, and after the image sensor **300** acquires part of a fingerprint image formed by each hole **411**, by later image extracting and processing, all parts of the fingerprint image are spliced and integrated into a complete and clear fingerprint image. To facilitate splicing of all the parts of the fingerprint image, a part of the fingerprint image formed by every two adjacent holes **411** includes a part of common fingerprint image.

Furthermore, for example, to allow the image sensor **300** to acquire part of the fingerprint image corresponding to each hole **411**, it is needed that the reflecting light of the fingerprints can reach the receiving surface of the image sensor **300**. As shown in FIG. **4**, it should satisfy a condition that an imaging angle θ is less than a total reflection angle, that is, $\theta < \arcsin(1/n)$, where n is a refractive index of a film layer in contact with the receiving surface of the image sensor **300**. For example, when the image sensor **300** is arranged on a bottom surface of the substrate **100**, n is a refractive index of the substrate **100**.

To allow the imaging to be in one pinhole imaging region **410**, as shown in FIG. **3a**, part of the fingerprint image formed by every two adjacent holes **411** includes a part of common fingerprint image, and it is required that the center distance d between the two adjacent holes **411** satisfies a formula: $d < 2 * (h_o + h_t/2) * \tan(\arcsin(1/n))$, where n is a refractive index of the film layer in contact with the receiving surface of the image sensor **300**, h_t is a thickness of the light shielding layer **400**, and h_o is a distance between an upper surface of the light shielding layer **400** and an upper surface **500** (namely a surface in contact with the fingerprints) of the OLED display panel.

In addition, in the OLED display panel provided by the embodiment of the present disclosure, to avoid overlapping between images of two adjacent holes **410** as shown in FIG. **3b**, and prevent difficulties to the later image extracting and processing, the center distance d between the two adjacent holes satisfies a formula: $d > 2 * (h_d + h_t/2) * \tan(\arcsin(1/n))$, where n is a refractive index of the film layer in contact with the receiving surface of the image sensor **300**, h_t is a thickness of the light shielding layer **400**, and h_d is a distance between a lower surface of the light shielding layer **400** and an upper surface of the image sensor **300**.

In the OLED display panel provided by the embodiment of the present disclosure, to improve imaging preciseness, such as preciseness of fingerprint recognition, it is needed to arrange each hole **411** as small as possible, but, if the hole **411** is too small, illuminance of the receiving surface of the image sensor **300** may be too low, leading to a difficulty to extract image data, thus, for example, the diameter of the hole **411** can be designed according to an internal structure of the OLED display panel and the light sensitivity of the image sensor **300** in use. For example, the diameter of each hole **411** is designed to be in a range from 5 μm and 20 μm , and, for example, the diameter of the hole **411** can be 5 μm .

For example, in the OLED display panel provided by the embodiment of the present disclosure, as shown in FIG. **1**,

the pinhole imaging region **410** and an OLED light-emitting device **200** closest to the pinhole imaging region **410** are constructed to meet a relationship: a horizontal distance a between the pinhole imaging region **410** and the OLED light-emitting device **200** closest to the pinhole imaging region **410** is larger than a vertical distance b between the pinhole imaging region **410** and the OLED light-emitting device **200** closest to the pinhole imaging region **410**, so as to avoid a situation that the light shielding layer **400** having the pinhole imaging region **410** is arranged below the film layer where the OLED light-emitting devices **200** are located, and the light emitted by the OLED light-emitting device **200** may affect the imaging of the pinhole imaging region **410**.

For example, in the OLED display panel provided by the embodiment of the present disclosure, as shown in FIG. **1**, the signal routing includes: data lines **600** arranged between the film layer where the OLED light-emitting devices are located and the substrate **100**, direct current voltage signal line(s), gate lines and the like. Besides, a source electrode and a drain electrode of a thin film transistor included in the control device are commonly arranged on a same layer as the data line(s) **600** and the direct current voltage signal line(s), and a gate electrode is commonly arranged on a same layer as the gate line(s).

In consideration of the imaging condition of the pinhole imaging region **410** and other factors, the light shielding layer **400** is adopted to shield stray light as much as possible and reduce effects of the stray light on pinhole imaging, so that the imaging quality can be improved. For example, the added light shielding layer **400** can be arranged between the film layer where the OLED light-emitting device **200** is located and the film layer where the data lines **600** are located; besides, to enable each OLED light-emitting device **200** to operate regularly, as shown in FIG. **1**, the light shielding layer **400** is provided with a connecting through hole **420** used for connecting other patterns (for example, a drain electrode or a pattern including the drain electrode) of a drain electrode of some transistor in the film layer where the data lines **600** are located with an anode **210** in the OLED light-emitting device **200**.

For a whole surface type film layer with holes in some portions, to prevent that the stray light may transmit through a position of the connecting through hole **420** of the light shielding layer **400** and the pinhole imaging is affected, for example, in the OLED display panel provided by the embodiment of the present disclosure, as shown in FIG. **1**, the anode **210** in the OLED light-emitting device **200** can be arranged into a layer stack structure including a light shielding metal film layer; for example, an ITO/Ag/ITO structure can be adopted to prepare the anode **210**; and in this case, the anode **210** of the OLED light-emitting device **200** is a light-proof film layer. In this way, the anode **210** can be utilized for shielding the connecting through hole **420** in the light shielding layer **400**, an orthographic projection of the anode **210** in the OLED light-emitting device **200** on the substrate **100** is made to cover an orthographic projection of the connecting through hole **420**; that is, the anode **210** and the light shielding layer **400** are overlapped in a direction perpendicular to the substrate **100**.

For example, in the OLED display panel provided by the embodiment of the present disclosure, the light shielding layer **400** is a whole surface type film layer with holes in some portions, the direct current voltage signal line(s) originally arranged on a same film layer as the data lines **600** can be omitted; that is, the signal routings included in the film layer where the data lines **600** are located are only the

data lines 600. The light shielding layer 400 is made of a conductive material, and the light shielding layer 400 is utilized to achieve function(s) of the direct current voltage signal line, that is, the light shielding layer 400 is a conductive layer used for loading direct current voltage signal(s). In this case, to avoid a short circuit between the light shielding layer 400 and the data lines 600, an insulating layer 700 can be added between the light shielding layer 400 and the film layer where the data lines 600 are located.

Compared with an instance that the data lines 600 and the direct current voltage signal line(s) are arranged on a same layer, the data lines 600 and the direct current voltage signal line(s) are both needed to be arranged at gap positions among the OLED light-emitting devices 200, in this way, to meet a requirement of alternating current loading (AC loading) of signal transmission of the data lines 600, the line width of the data line 600 is required to be made narrower, and to reduce the electrical resistance, the film layer where the data lines are located is thicker. Functions of the direct current voltage signal line(s) are transferred to the light shielding layer 400, in this way, the arrangement space of the data lines 600 in the film layer can be increased, and the electrical resistance value is reduced. For example, in an instance that the data lines 600 and the direct current voltage signal line(s) are arranged on a same layer, the line width of each data line 600 is 2.3 μm , and the thickness is 750 nm; after the functions of the direct current voltage signal line(s) are transferred to the light shielding layer, the line width of the data line 600 can be larger than 2.3 μm , and the thickness of the film layer where the data lines 600 are located can be less than 700 nm. For example, the line width of the data line 600 can be 3.5 μm , and the thickness of the film layer where the data lines 600 are located can be reduced to 500 nm.

Furthermore, for example, in the OLED display panel provided by the embodiment of the present disclosure, in an example that the light shielding layer 400 is a conductive layer used for loading a direct current voltage signal, as shown in FIG. 1, a hollow region 430 above at least part of the data line can be arranged in the light shielding layer 400, that is, under a condition that continuity of a film layer of the light shielding layer 400 is permitted, a hole can be formed in the light shielding layer 400 above the data line 600 so as to reduce the overlapping capacitance of the light shielding layer 400 and the data line 600, and avoid a possible signal mutual interference. In this case, to avoid effects of the stray light on the pinhole imaging through the hollow area 430, when the anode 210 of the OLED light-emitting device 200 is a light-proof film layer, the anode 210 can be utilized for shielding the hollow region 430 in the light shielding layer 400, so that an orthographic projection of the anode 210 in the OLED light-emitting device 200 on the substrate 100 is made to cover an orthographic projection of the hollow region 430.

Furthermore, for example, in the OLED display panel provided by the embodiment of the present disclosure, an effect of shielding the stray light through the hollow region 430 in the light shielding layer 400 and the connecting through hole 420 is achieved by increasing the area of the anode 210 of the OLED light-emitting device 200. For example, the above requirement can be met only by increasing the area of the anode 210 in the OLED light-emitting device(s) 200, that is, to keep a relative proportion relationship of light-emitting colors, the area of the light-emitting layer 220 (EL) in the OLED light-emitting device(s) 200 is not changed, in this case, the area of the anode 210 in the

OLED light-emitting device(s) 200 can be larger than the area of the light-emitting layer 220 in the OLED light-emitting device(s) 200.

Under a same innovative concept, an embodiment of the present disclosure also provides a display device, comprising the OLED display panel provided by the embodiment of the present disclosure. The display device can be any product or component with a display function, such as a mobile phone, a tablet personal computer, a TV set, a display, a notebook computer, a digital photo frame, a navigator or the like. Implementation of the display device can refer to the embodiments of the OLED display panel, which would not be described for the repeated details.

According to the OLED display panel and the display device provided by the embodiments of the present disclosure, the image sensor is added below the OLED light-emitting device, and the light shielding layer having at least one pinhole imaging region is added between the image sensor and the OLED light-emitting device. By arranging the pinhole imaging region corresponding to the gap position between the OLED light-emitting devices in the light shielding layer and staggered from the light shielding parts in the signal routing and the control device, the object located above the OLED display panel is imaged on the image sensor, and when a finger is placed above the OLED display panel corresponding to the pinhole imaging region, the fingerprint acquiring and recognizing function can be achieved. In this way, the fingerprint recognition function can be achieved in the active area of the OLED display panel, and the attached regions of the whole device are reduced, so that a bezelless design is achieved.

The described above are only exemplary embodiments of the present disclosure, and the present disclosure is not intended to be limited thereto. For one of ordinary skill in the art, various changes and alternations may be readily contemplated without departing from the technical scope of the present disclosure, and all of these changes and alternations shall fall within the scope of the present disclosure.

The present application claims priority of Chinese Patent Application No. 201611207500.8 filed on Dec. 23, 2016 to SIPO and entitled "An OLED display panel and a display device," the disclosure of which is incorporated herein by reference in its entirety.

What is claimed is:

1. An OLED display panel, comprising:

a substrate;

a plurality of OLED light-emitting devices arranged on a side of the substrate;

a signal routing and a control device correspondingly connected with the OLED light-emitting devices;

an image sensor arranged on the other side or the same side of the substrate; and

a light shielding layer arranged between the image sensor and a film layer where the OLED light-emitting devices are located, the light shielding layer comprising at least one pinhole imaging region;

wherein an orthographic projection position of the pinhole imaging region on the substrate is arranged at a gap position between the OLED light-emitting devices, and is staggered from orthographic projection positions of light shielding parts in the signal routing and the control device on the substrate;

the image sensor is configured to acquire an image formed after an object above the OLED display panel passes through the pinhole imaging region;

the signal routing comprises a data line arranged between the film layer where the OLED light-emitting devices are located and the substrate;

the light shielding layer is arranged between the film layer where the OLED light-emitting devices are located and a film layer where the data line is located; and

the light shielding layer further comprises: a connecting through hole configured to connect a drain electrode in the film layer where the data line is located, or a pattern comprising the drain electrode with an anode in the OLED light-emitting device.

2. The OLED display panel according to claim 1, wherein the pinhole imaging region comprises a plurality of holes distributed in an array.

3. The OLED display panel according to claim 2, wherein, in a pinhole imaging region, a center distance d between every two adjacent holes satisfies one of the following or a combination relationship:

$$d < 2 * (h_o + h_s / 2) * \tan(\arcsin(1/n)), d > 2 * (h_d + h_s / 2) * \tan(\arcsin(1/n));$$

where n is a refractive index of a film layer in contact with a receiving surface of the image sensor, h_d is a distance between a lower surface of the light shielding layer and an upper surface of the image sensor, h_s is a thickness of the light shielding layer, and h_o is a distance between an upper surface of the light shielding layer and an upper surface of the OLED display panel.

4. The OLED display panel according to claim 3, wherein each hole has a diameter in a range of 5 μm to 20 μm .

5. The OLED display panel according to claim 2, wherein each hole has a diameter in a range of 5 μm to 20 μm .

6. The OLED display panel according to claim 1, wherein the pinhole imaging region and a corresponding OLED light-emitting device of the closest to the pinhole imaging region satisfy a following relationship:

a horizontal distance between the pinhole imaging region and the corresponding OLED light-emitting device closest to the pinhole imaging region is larger than a vertical distance between the pinhole imaging region and the corresponding OLED light-emitting device closest to the pinhole imaging region.

7. The OLED display panel according to claim 1, wherein the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer; and

an orthographic projection of the anode in the OLED light-emitting device on the substrate covers an orthographic projection of the connecting through hole.

8. The OLED display panel according to claim 7, wherein the anode in the OLED light-emitting device has an area larger than that of a light-emitting layer in the OLED light-emitting device.

9. The OLED display panel according to claim 1, wherein the signal routing included in the film layer where the data line is located is a data line; and

the light shielding layer is a conductive layer configured to load a direct current voltage signal.

10. The OLED display panel according to claim 9, wherein the light shielding layer further comprises a hollow region arranged above at least a part of the data line; and

the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer, and an orthographic projection of the anode on the substrate covers an orthographic projection of the hollow region.

11. The OLED display panel according to claim 9, wherein the data line has a line width larger than 2.3 μm , and the film layer where the data line is located has a thickness less than 700 nm.

12. The OLED display panel according to claim 11, wherein the line width of the data line is 3.5 μm , and the thickness of the film layer where the data line is located is 500 nm.

13. The OLED display panel according to claim 1, wherein the image sensor is arranged in a whole surface manner, or is only arranged below the pinhole imaging region.

14. The OLED display panel according to claim 1, wherein the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer; and

an orthographic projection of the anode in the OLED light-emitting device on the substrate covers an orthographic projection of the connecting through hole.

15. The OLED display panel according to claim 1, wherein the signal routing included in the film layer where the data line is located is a data line; and

the light shielding layer is a conductive layer configured to load a direct current voltage signal.

16. The OLED display panel according to claim 15, wherein the light shielding layer further comprises a hollow region arranged above at least a part of the data line; and

the anode in the OLED light-emitting device comprises a layer stack structure comprising a light shielding metal film layer, and an orthographic projection of the anode on the substrate covers an orthographic projection of the hollow region.

17. A display device, comprising an OLED display panel, wherein the OLED display panel comprises:

a substrate;

a plurality of OLED light-emitting devices arranged on a side of the substrate;

a signal routing and a control device correspondingly connected with the OLED light-emitting devices;

an image sensor arranged on the other side or the same side of the substrate; and

a light shielding layer arranged between the image sensor and a film layer where the OLED light-emitting devices are located, the light shielding layer comprising at least one pinhole imaging region;

wherein an orthographic projection position of the pinhole imaging region on the substrate is arranged at a gap position between the OLED light-emitting devices, and is staggered from orthographic projection positions of light shielding parts in the signal routing and the control device on the substrate;

the image sensor is configured to acquire an image formed after an object above the OLED display panel passes through the pinhole imaging region;

the signal routing comprises a data line arranged between the film layer where the OLED light-emitting devices are located and the substrate;

the light shielding layer is arranged between the film layer where the OLED light-emitting devices are located and a film layer where the data line is located; and

the light shielding layer further comprises: a connecting through hole configured to connect a drain electrode in the film layer where the data line is located, or a pattern comprising the drain electrode with an anode in the OLED light-emitting device.

专利名称(译)	OLED显示面板及显示装置		
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摘要(译)

提供了一种OLED显示面板和显示装置。在OLED发光器件下方添加图像传感器，在图像传感器与OLED发光器件之间添加包括至少一个针孔成像区域的遮光层，该针孔成像区域对应于OLED光之间的间隙位置。遮光层中的发光器件和信号路由中的遮光部分错开，以及控制装置中，位于OLED显示面板上方的物体被成像在图像传感器上。

